

**LIST OF REFERENCES CITED BY APPLICANT(S)**  
(See several Sheets if necessary)

ATTY DOCKET NO.

35 G15122

APPLICATION NO.

09/779 645

MAY 19 2001

February 9, 2001

2812

U.S. PATENT DOCUMENTS

## FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO OR ABSTRACT
B+	5275326	10/22/93	Japan			Abstract
B+	2000-12521	1/14/00	Japan			Abstract

OpenDocument (Author: Tia, Date: 2019-01-25)

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Sheet 1 of 1

FORM PTO-114P (Qualified)

U.S. DEPARTMENT OF COMMERCE  
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LIST OF REFERENCES CITED BY APPLICANT(S)  
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ATTY DOCKET NO.  
35.C15122APPLICATION NO.  
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APPLICANT

SHIGENORI ISHIHARA

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## 5. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

RECEIVED  
JUL 25 2001  
TC 1700

## FOREIGN PATENT DOCUMENTS

DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO OR ABSTRACT

## OTHER DOCUMENT(S) (including Author, Title, Date, Patent/Prints, Etc.)

B/T	S. Fujimura et al., "Ion Implantation Change in the Chemical Structure of a Resist", Nuclear Instruments and Methods in Physics Research B39 (1989), pp. 809-812.

EXAMINER

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(EXAMINER) Initial if reference considered, whether or not citation is in conformance with MPEP 608. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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